EG1ME

Glass Passivated Junction Ultra Fast Recovery Plastic Rectifiers VOLTAGE:1000V CURRENT: 1.0A



FEATURE

MECHANICAL DATA

Mounting position: any

Retardant Epoxy

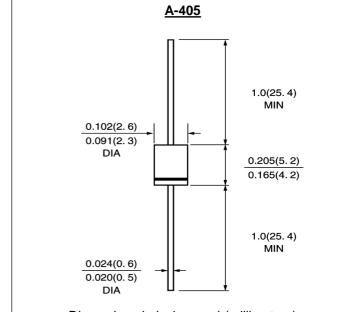
Polarity: color band denotes cathode

Low power loss High surge capability Glass passivated chip junction Ultra-fast recovery time for high efficiency High temperature soldering guaranteed 250°C/10sec/0.375″ lead length at 5 lbs tension

Terminal: Plated axial leads solderable per

MIL-STD 202E, method 208C

Case: Molded with UL-94 Class V-0 recognized Flame



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

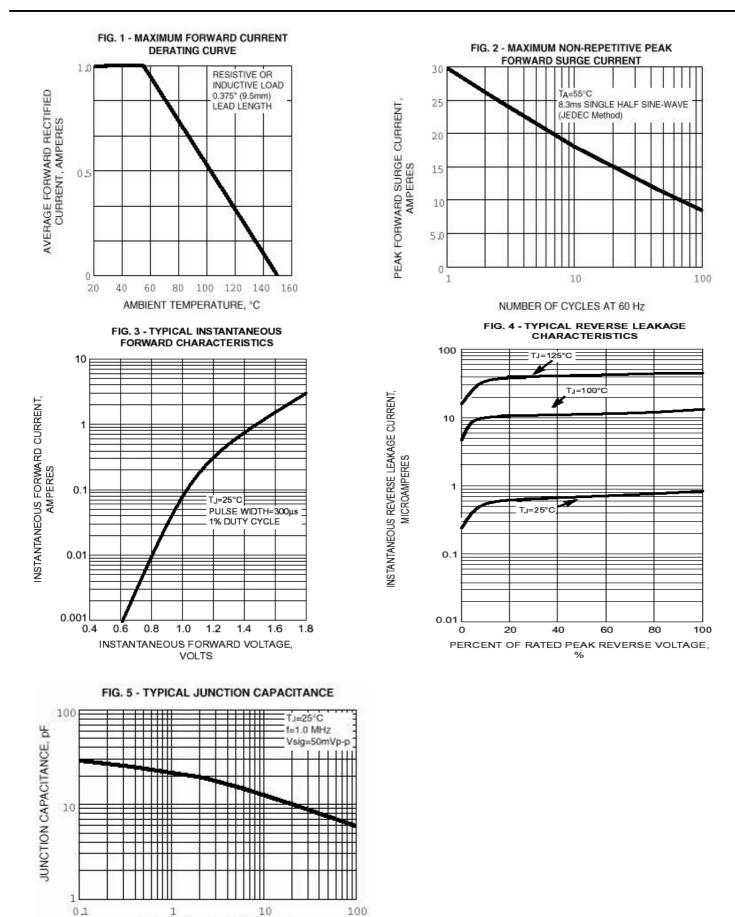
	SYMBOL	EG1ME	unit
Maximum Recurrent Peak Reverse Voltage	Vrrm	1000	V
Maximum RMS Voltage	Vrms	700	V
Maximum DC blocking Voltage	Vdc	1000	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta =55°C	lf(av)	1.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	lfsm	30	A
Maximum Forward Voltage at rated Forward Current and 25°C	Vf	1.7	V
Maximum full load reverse current full cycle average at 55°C Ambient	lr(av)	50	μΑ
Maximum DC Reverse CurrentTa = $25^{\circ}C$ at rated DC blocking voltageTa = $125^{\circ}C$	Ir	10 100	μ <i>Α</i> μ <i>Α</i>
Maximum Reverse Recovery Time (Note 1)	Trr	75	nS
Typical Junction Capacitance (Note 2)	Cj	15	pF
Typical Thermal Resistance (Note 3)	Rth(ja)	60	° (//
Storage and Operating Temperature Range	Tstg, Tj	-55 to +150	° (

Note:

1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted



100

RATINGS AND CHARACTERISTIC CURVES EG1ME

1

REVERSE VOLTAGE, VOLTS

10

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